Rectifier diode



For surface mount applications		
Low profile package		
Glass passivated chip junction		
SPECIFICATION:		
Peak off-state voltage	100 V	
Forward current	1.0 A	
Recovery time	50 ns	
Housing type	SMA	
Configuration	Single	
Operating temperature	-55+150 °C	
Conducting-state voltage	1.0 V	
Off-state current	5 μΑ	



Art. Nr. RND US1B-AT



